



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## 2SC6097 — NPN Epitaxial Planar Silicon Transistor High-Current Switching Applications

### Applications

- DC / DC converter, relay drivers, lamp drivers, motor drivers, inverter

### Features

- Adoption of FBET, MBIT process
- Low collector-to-emitter saturation voltage
- High allowable power dissipation
- Large current capacity
- High-speed switching

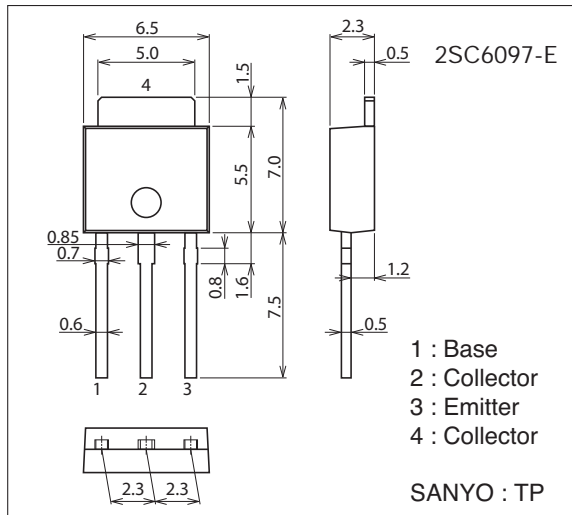
### Specifications

Absolute Maximum Ratings at Ta=25°C

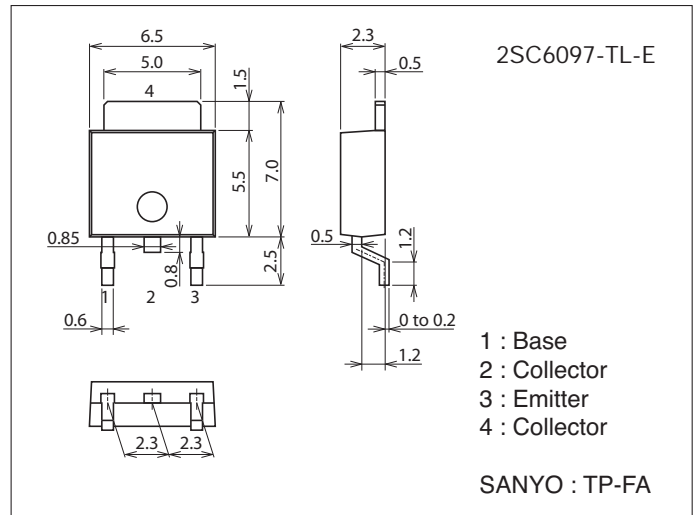
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		100	V
Collector-to-Emitter Voltage	VCES		100	V
Collector-to-Emitter Voltage	VCEO		60	V
Emitter-to-Base Voltage	VEBO		6.5	V
Collector Current	IC		3	A
Collector Current (Pulse)	ICP		5	A
Base Current	IB		600	mA

Continued on next page.

Package Dimensions unit : mm (typ)  
7518-003



Package Dimensions unit : mm (typ)  
7003-003

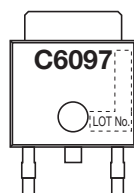


### Product & Package Information

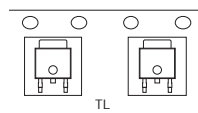
- Package : TP
- JEITA, JEDEC : SC-64, TO-251
- Minimum Packing Quantity : 500 pcs./bag

- Package : TP-FA
- JEITA, JEDEC : SC-63, TO-252
- Minimum Packing Quantity : 700 pcs./reel

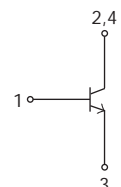
### Marking (TP, TP-FA)



### Packing Type (TP-FA) : TL



### Electrical Connection



## 2SC6097

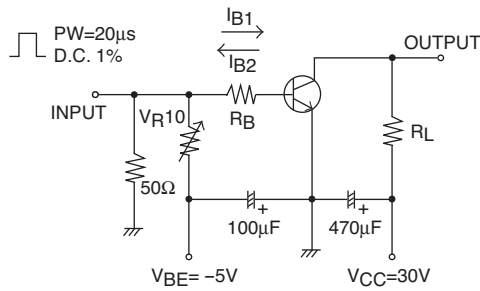
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Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	PC		0.8	W
		T <sub>c</sub> =25°C	15	W
Junction Temperature	T <sub>j</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Electrical Characteristics at T<sub>a</sub>=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =50V, I <sub>E</sub> =0A			1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			1	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA	300		600	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =500mA		390		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		18		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)1</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =50mA		100	150	mV
	V <sub>CE(sat)2</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =100mA		90	135	mV
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =100mA		0.84	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0A	100			V
Collector-to-Emitter Breakdown Voltage	V(BR)CES	I <sub>C</sub> =100μA, R <sub>BE</sub> =0Ω	100			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	60			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =10μA, I <sub>C</sub> =0A	6.5			V
Turn-On Time	t <sub>on</sub>	See specified Test Circuit		35		ns
Storage Time	t <sub>stg</sub>			680		ns
Fall Time	t <sub>f</sub>			24		ns

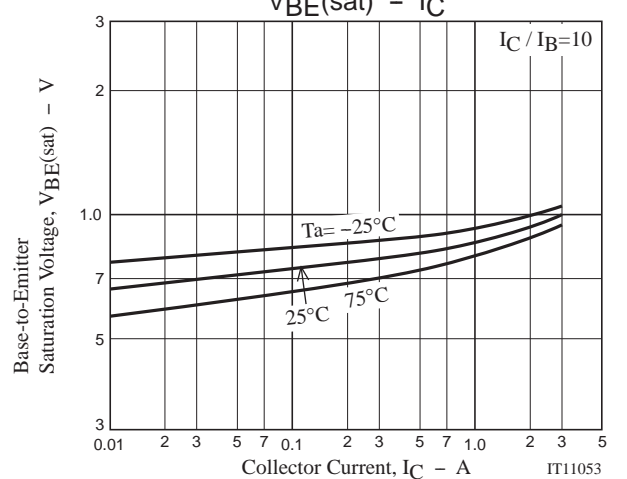
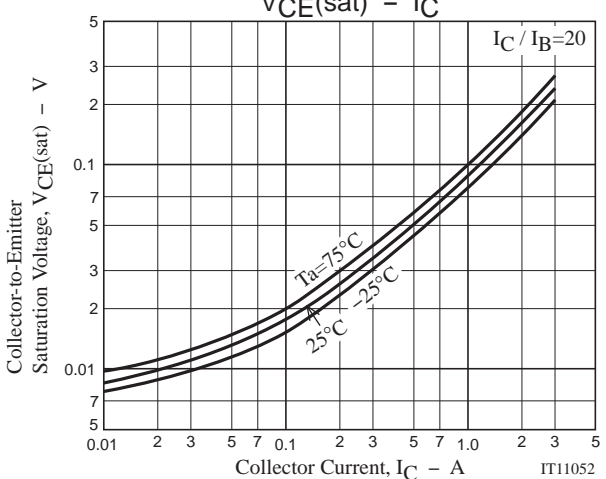
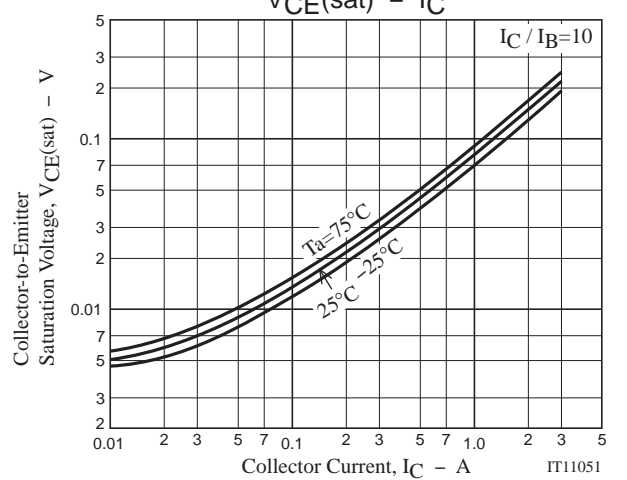
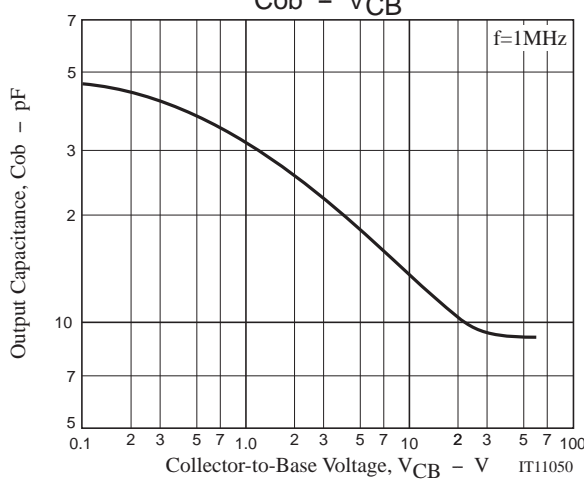
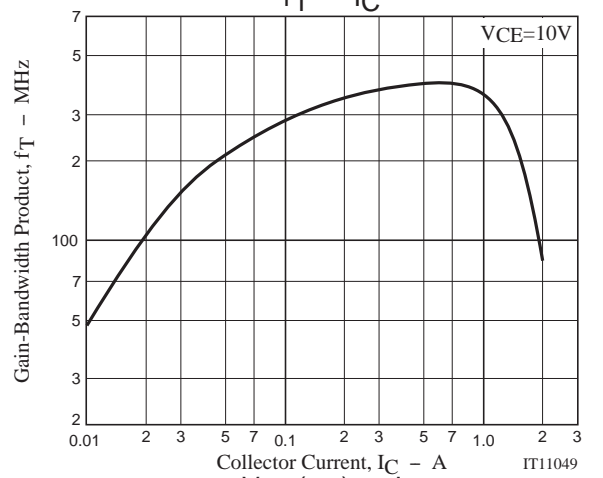
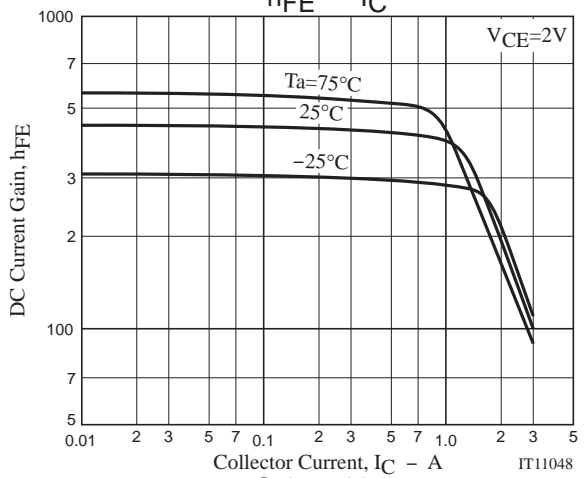
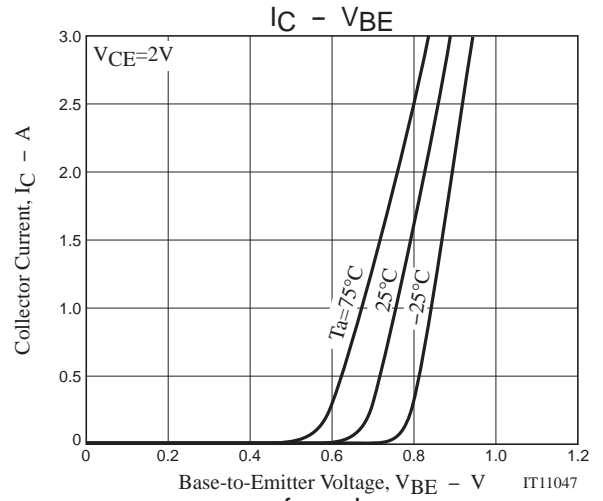
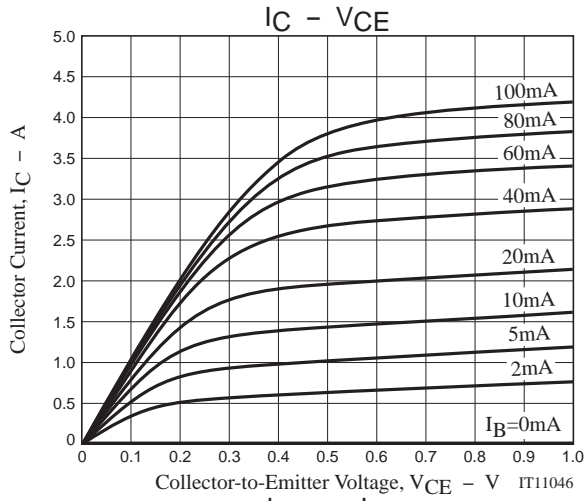
### Switching Time Test Circuit

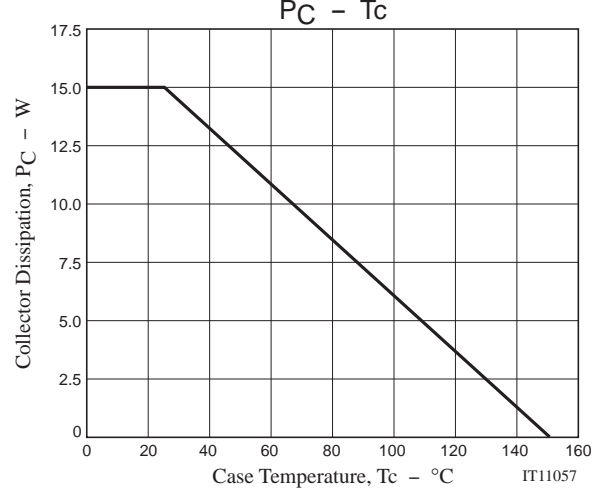
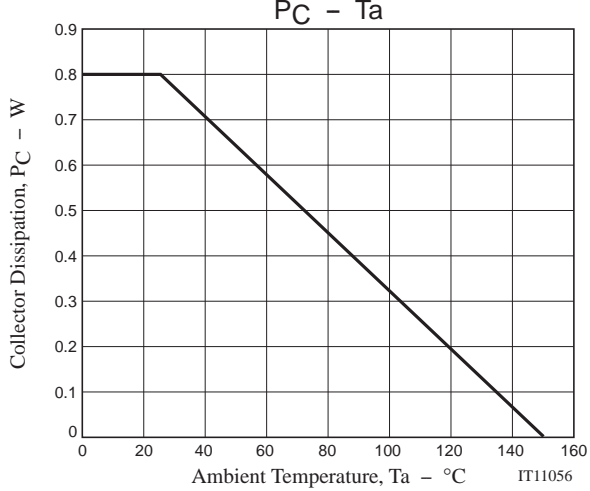
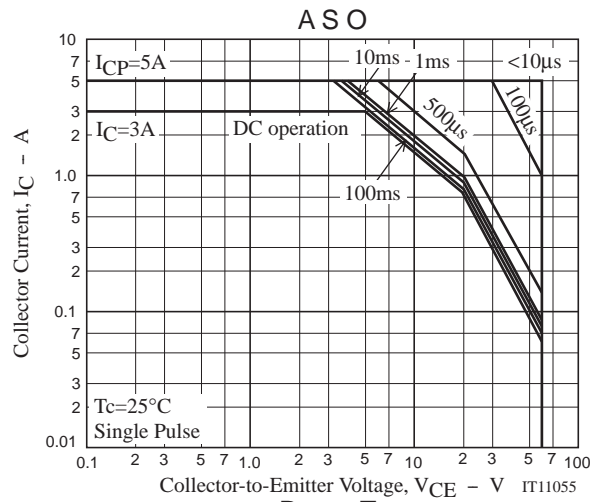
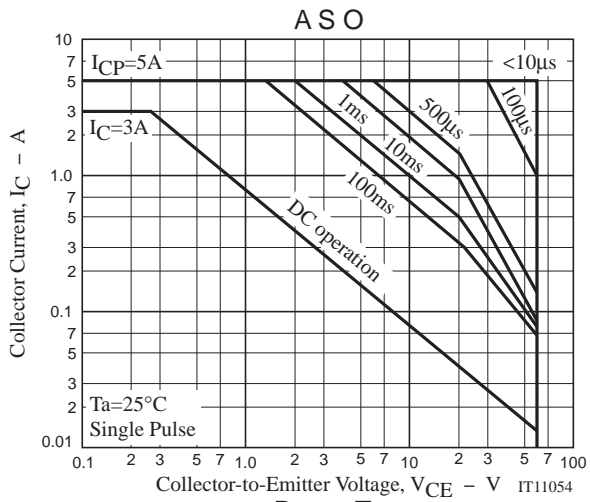


$$I_C = 10I_{B1} = -10I_{B2} = 0.5A$$

### Ordering Information

Device	Package	Shipping	memo
2SC6097-E	TP	500pcs./bag	Pb Free
2SC6097-TL-E	TP-FA	700pcs./reel	Pb Free





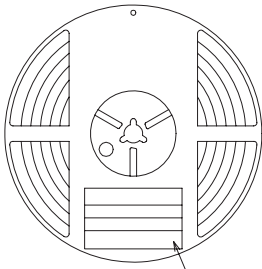
Taping Specification

2SC6097-TL-E

Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
TP-FA	TP	700	2,100	12,600	3 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

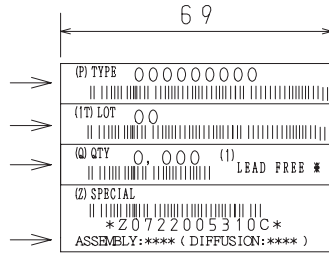
Packing method



Type No.  
LOT No.  
Quantity  
Origin

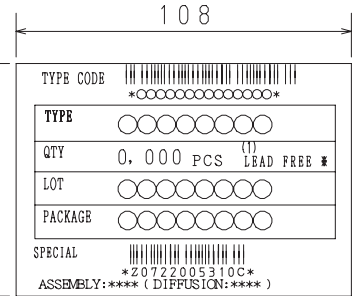
Reel label

Reel label, Inner box label (unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



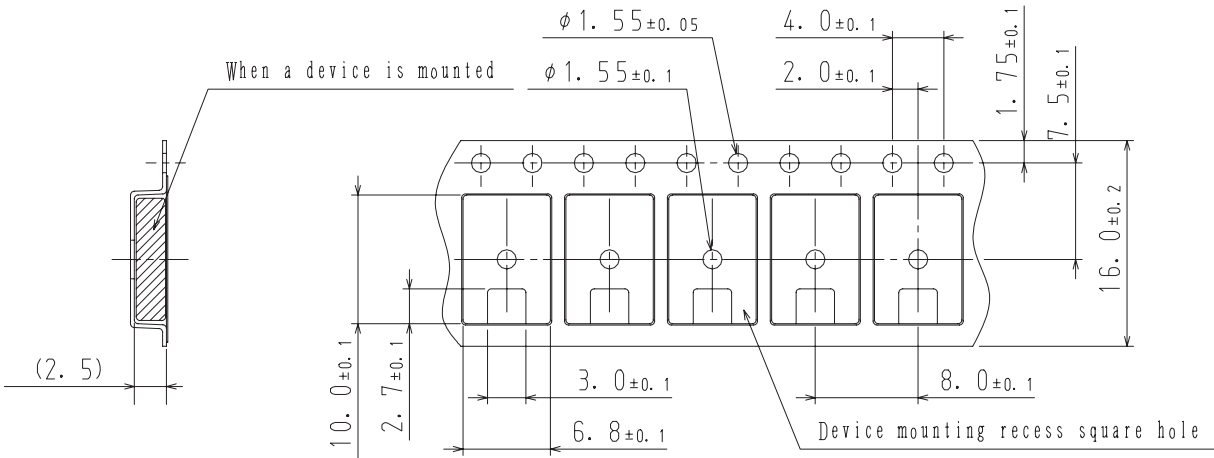
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

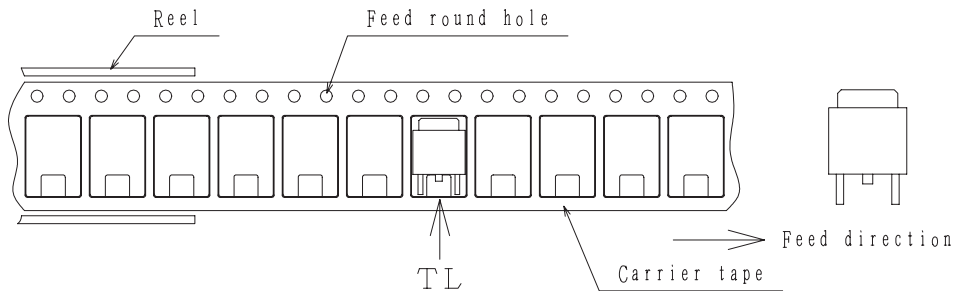
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

Taping configuration

1. Carrier tape size (unit:mm)



2. Device placement direction

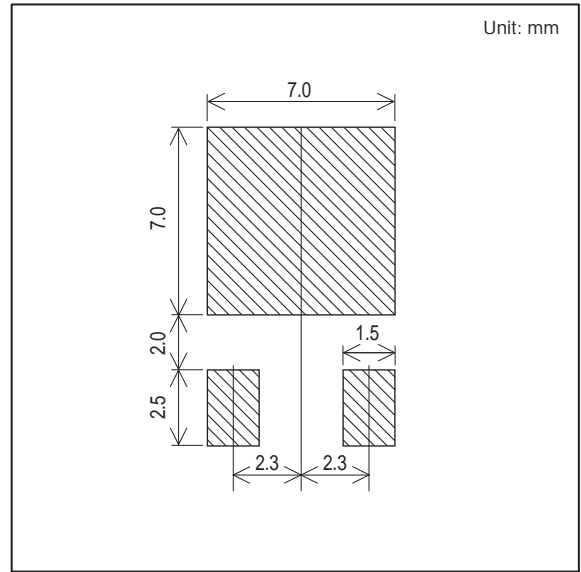
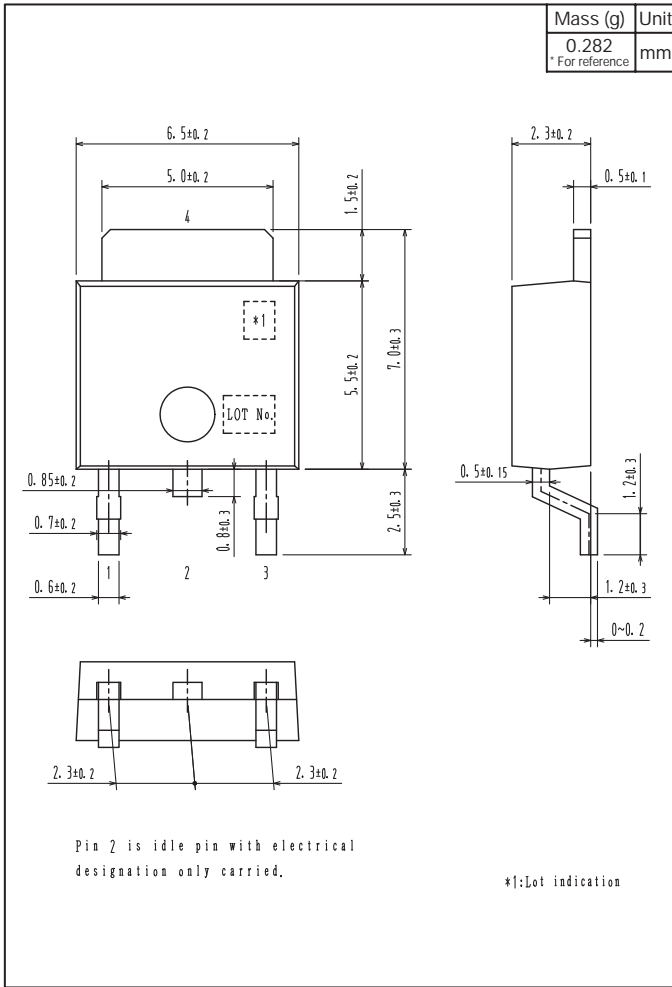


Those with one electrode terminal on the feed hole side.....TL

Outline Drawing

2SC6097-TL-E

Land Pattern Example



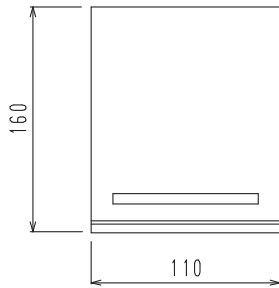
Bag Packing Specification

2SC6097-E

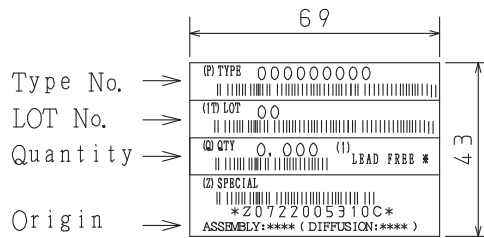
1. Packing Format

Package Name	Maximum Number of devices contained (pcs)			
	Bag	Inner box	Outer box	
TP	500	B-1	A-1	A-2
		10,000	50,000	30,000
	Packing format (Dimensions:mm (external))			
		Inner box	Outer box	
		B-1	A-1	A-2
		445×225×55	470×250×300	470×250×190

2. Bag dimensions  
(unit:mm)



3. Bag label, Inner box label  
(unit:mm)



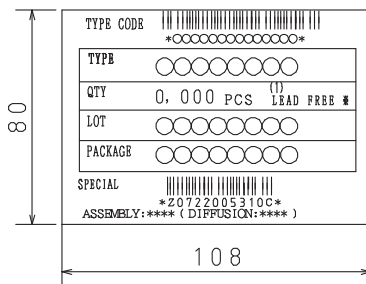
4. Outer box label  
(unit:mm)

It is a label at the time of factory shipments,  
The form of a label may change in physical  
distribution process,

NOTE (1)

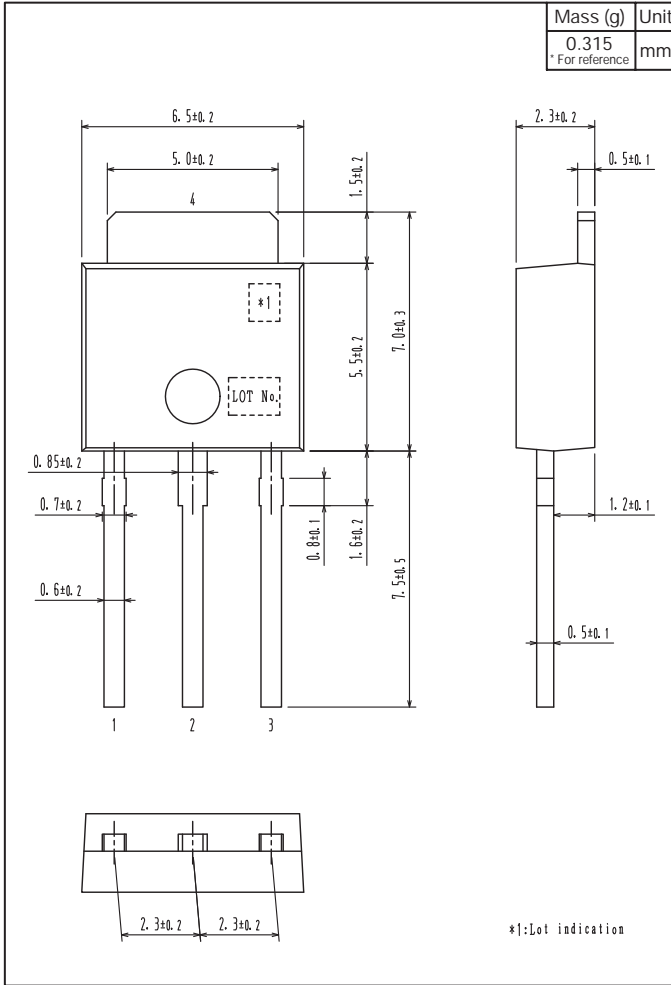
The LEAD FREE \* description shows that the  
surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3



Outline Drawing

2SC6097-E





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